

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#5/A

Application Serial No. . . . . Unknown  
Filing Date . . . . . December 4, 2000  
Inventor . . . . . Charles H. Dennison  
Assignee . . . . . Micron Technology, Inc.  
Group Art Unit . . . . . Unknown  
Examiner . . . . . Unknown  
Attorney's Docket No. . . . . MI22-1577  
Title: Field Effect Transistors, Integrated Circuitry, Methods of Forming Field Effect Transistor Gates, and Methods of Forming Integrated Circuitry

PRELIMINARY AMENDMENT

To: Box Patent Application  
Assistant Commissioner for Patents  
Washington, D.C. 20231

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Please enter the following amendments prior to examining the above-identified application.

AMENDMENTSIn the Specification

At p. 1 before the "Technical Field" section, please insert the following:

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--RELATED PATENT DATA

This patent resulted from a continuation application of U.S. Patent Application Serial No. 09/138,150, filed August 21, 2000, entitled "Field Effect